IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re	U.S. Patent Application of)
SATO	et al.)
Appli	cation Number: To be Assigned)
Filed: Concurrently Herewith)
For:	MANUFACTURING METHOD OF SEMICONDUCTOR LASER DIODE)
ATTO	RNEY DOCKET NO. NITT.0191)

Honorable Assistant Commissioner for Patents
Washington, D.C. 20231

PRELIMINARY AMENDMENT

Sir:

Applicant has amended the claims in order to correct the claims in accordance with standard U.S. practice. Prior to an examination on the merits, please amend the above-identified application as follows: